

# ELM75xxxxB CMOS Small package voltage detector

## ■ General description

ELM75xxxxB is CMOS voltage detector with lower current consumption : Typ.  $0.6\mu\text{A}$  ( $V_{\text{dd}}=4.5\text{V}$ ) and higher accuracy ( $\pm 2.0\%$ ) of detection voltage. It consists of very low-power-consumption reference voltage source, hysteresis comparator, output driver and detection voltage setting resistor. The output is positive logic; therefore, the output becomes low level when  $V_{\text{dd}}$  is lower than detection voltage. There are two output styles of ELM75 series: N-ch opendrain and CMOS output. The standard voltages are 2.2V, 2.7V, and 3.5V; ELM75 series can also be made as semi-custom IC within the range of 1.4V~5.5V by 0.1V step.

## ■ Features

- Detection voltage range : 1.4V~5.5V (by 0.1V)
- Low current consumption : Typ.  $0.6\mu\text{A}$  ( $V_{\text{dd}}=4.5\text{V}$ )
- Low voltage operation : Reset operation assured at 0.8V
- Accuracy of detection voltage :  $\pm 2.0\%$
- Low temperature coefficient : Typ.  $+100\text{ppm}/^{\circ}\text{C}$
- Package : SOT-89, SOT-23, SC-82AB  
SC-70(SOT-323)

## ■ Application

- Reset for microcomputers
- Voltage power shortage detectors
- Switch of back-up power source
- Battery checkers

## ■ Maximum absolute ratings

| Parameter             | Symbol           | Limit  | Unit               |
|-----------------------|------------------|--|--------------------|
| Power supply voltage  | V <sub>dd</sub>  | 10   | V                  |
| Output voltage        | V <sub>out</sub> | N-ch : V <sub>ss</sub> -0.3~+10<br>CMOS: V <sub>ss</sub> -0.3~V <sub>dd</sub> +0.3 | V                  |
| Output current        | I <sub>out</sub> | 20   | mA                 |
| Power dissipation     | P <sub>d</sub>   | 300 (SOT-89)<br>200 (SOT-23)<br>150 (SC-82AB)<br>150 (SC-70)(SOT-323)              | mW                 |
| Operating temperature | T <sub>op</sub>  | -40~+85  | $^{\circ}\text{C}$ |
| Storage temperature   | T <sub>stg</sub> | -55~+125   | $^{\circ}\text{C}$ |

## ■ Selection guide

### ELM75xxxxB-x

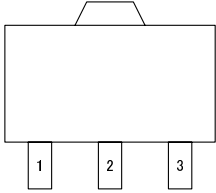
| Symbol |                   |  |
|--------|-------------------|--|
| a,b    | Detection voltage | e.g. :<br>22: V <sub>detn</sub> =2.2V 23: V <sub>detn</sub> =2.3V<br>27: V <sub>detn</sub> =2.7V 35: V <sub>detn</sub> =3.5V |
| c      | Output form       | N : N-ch opendrain<br>C : CMOS   |
| d      | Package           | A : SOT-89 B : SOT-23<br>C : SC-82AB<br>D : SOT-89(Reverse pin assign)<br>E : SC-70(SOT-323)                                 |
| e      | Product version   | B  |
| f      | Taping direction  | S : Refer to PKG file<br>N : Refer to PKG file   |

ELM75 x x x x B - x  
 $\uparrow \uparrow \uparrow \uparrow \uparrow \uparrow$   
 a b c d e f

# ELM75xxxxB CMOS Small package voltage detector

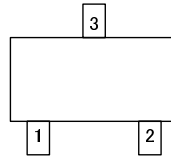
## Pin configuration

SOT-89 (TOP VIEW)



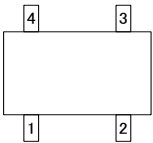
| Pin No. | Pin name<br>75xxxAB | Pin name<br>75xxxDB |
|---------|---------------------|---------------------|
| 1       | OUT                 | VDD                 |
| 2       | VDD                 | VSS                 |
| 3       | VSS                 | OUT                 |

SOT-23 (TOP VIEW)



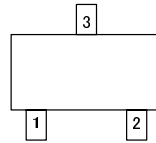
| Pin No. | Pin name |
|---------|----------|
| 1       | OUT      |
| 2       | VSS      |
| 3       | VDD      |

SC-82AB (TOP VIEW)



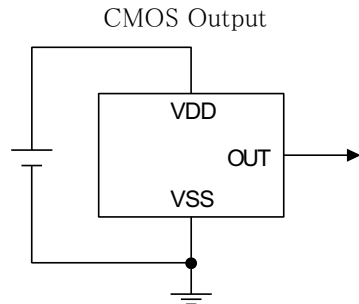
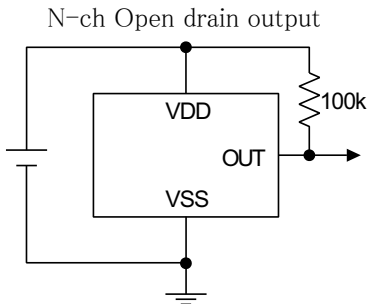
| Pin No. | Pin name |
|---------|----------|
| 1       | OUT      |
| 2       | VDD      |
| 3       | NC       |
| 4       | VSS      |

SC-70 (TOP VIEW)

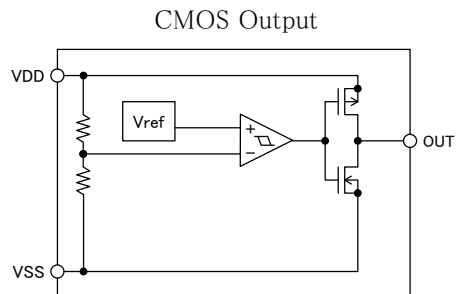
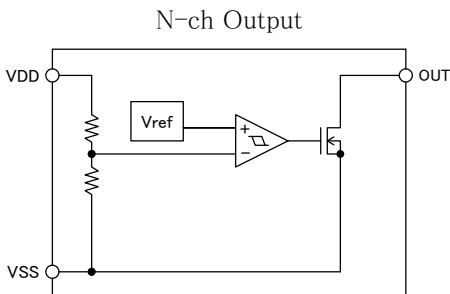


| Pin No. | Pin name |
|---------|----------|
| 1       | OUT      |
| 2       | VSS      |
| 3       | VDD      |

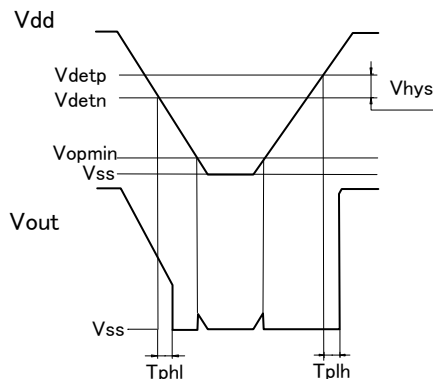
## Standard circuit



## Block diagram



## ■ Timing chart



## ■ Electrical characteristics

Vdetn=2.2V (ELM7522xxB)

Top=25°C

| Parameter                           | Symbol                               | Condition           | Min.            | Typ.            | Max.            | Unit   | Note  |
|-------------------------------------|--------------------------------------|---------------------|-----------------|-----------------|-----------------|--------|-------|
| Detection voltage                   | Vdetn                                |                     | 2.156           | 2.200           | 2.244           | V      | 2     |
| Hysteresis width                    | Vphys                                |                     | Vdetn<br>× 0.02 | Vdetn<br>× 0.04 | Vdetn<br>× 0.08 | V      | 2     |
| Current consumption                 | I <sub>ss</sub>                      | Vdd=3.0V            |                 | 0.6             | 2.0             | μA     | 1     |
| Power voltage                       | Vdd                                  |                     | 0.8             |                 | 6.0             | V      | 2     |
| Output current                      | I <sub>outn</sub>                    | Vdd=0.95V, Vds=0.4V | 0.03            | 0.12            |                 | mA     | 3-(1) |
|                                     |                                      | Vdd=1.40V, Vds=0.4V | 0.60            | 1.40            |                 |        |       |
|                                     | I <sub>outp</sub>                    | Vdd=3.00V, Vds=0.4V | 0.15            | 0.40            |                 |        | 3-(2) |
| Delay time                          | T <sub>plh</sub>                     | Vdd=0.95V~3.00V     |                 | 10              |                 | μs     | 4     |
|                                     | T <sub>phl</sub>                     | Vdd=3.00V~0.95V     |                 | 10              |                 |        |       |
| Temperature characteristic of Vdetn | $\frac{\Delta V_{detn}}{\Delta Top}$ | Top=-40~+85°C       |                 | +100            |                 | ppm/°C |       |

\* I<sub>outp</sub> cannot be applied to N-ch opendrain output products. \* Note : test circuit No.

Vdetn=2.3V (ELM7523xxB)

Top=25°C

| Parameter                           | Symbol                               | Condition           | Min.            | Typ.            | Max.            | Unit   | Note  |
|-------------------------------------|--------------------------------------|---------------------|-----------------|-----------------|-----------------|--------|-------|
| Detection voltage                   | Vdetn                                |                     | 2.254           | 2.300           | 2.346           | V      | 2     |
| Hysteresis width                    | Vphys                                |                     | Vdetn<br>× 0.02 | Vdetn<br>× 0.04 | Vdetn<br>× 0.08 | V      | 2     |
| Current consumption                 | I <sub>ss</sub>                      | Vdd=3.0V            |                 | 0.6             | 2.0             | μA     | 1     |
| Power voltage                       | Vdd                                  |                     | 0.8             |                 | 6.0             | V      | 2     |
| Output current                      | I <sub>outn</sub>                    | Vdd=0.95V, Vds=0.4V | 0.03            | 0.12            |                 | mA     | 3-(1) |
|                                     |                                      | Vdd=1.40V, Vds=0.4V | 0.60            | 1.40            |                 |        |       |
|                                     | I <sub>outp</sub>                    | Vdd=3.00V, Vds=0.4V | 0.15            | 0.40            |                 |        | 3-(2) |
| Delay time                          | T <sub>plh</sub>                     | Vdd=0.95V~3.00V     |                 | 10              |                 | μs     | 4     |
|                                     | T <sub>phl</sub>                     | Vdd=3.00V~0.95V     |                 | 10              |                 |        |       |
| Temperature characteristic of Vdetn | $\frac{\Delta V_{detn}}{\Delta Top}$ | Top=-40~+85°C       |                 | +100            |                 | ppm/°C |       |

\* I<sub>outp</sub> cannot be applied to N-ch opendrain output products. \* Note : test circuit No.

# ELM75xxxxB CMOS Small package voltage detector

Vdetn=2.4V (ELM7524xxB)

Top=25°C

| Parameter                           | Symbol                               | Condition                                     | Min.           | Typ.           | Max.           | Unit   | Note  |
|-------------------------------------|--------------------------------------|---|----------------|----------------|----------------|--------|-------|
| Detection voltage                   | Vdetn                                |   | 2.352          | 2.400          | 2.448          | V      | 2     |
| Hysteresis width                    | Vhys                                 |   | Vdetn<br>×0.02 | Vdetn<br>×0.04 | Vdetn<br>×0.08 | V      | 2     |
| Current consumption                 | I <sub>ss</sub>                      | V <sub>dd</sub> =3.0V                         |                | 0.6            | 2.0            | μA     | 1     |
| Power voltage                       | V <sub>dd</sub>                      |   | 0.8            |                | 6.0            | V      | 2     |
| Output current                      | I <sub>outn</sub>                    | V <sub>dd</sub> =0.95V, V <sub>ds</sub> =0.4V | 0.03           | 0.12           |                | mA     | 3-(1) |
|                                     |                                      | V <sub>dd</sub> =1.40V, V <sub>ds</sub> =0.4V | 0.60           | 1.40           |                |        |       |
|                                     | I <sub>outp</sub>                    | V <sub>dd</sub> =3.00V, V <sub>ds</sub> =0.4V | 0.15           | 0.40           |                |        | 3-(2) |
| Delay time                          | T <sub>plh</sub>                     | V <sub>dd</sub> =0.95V~3.00V                  |                | 10             |                | μs     | 4     |
|                                     | T <sub>p<sub>hl</sub></sub>          | V <sub>dd</sub> =3.00V~0.95V                  |                | 10             |                |        |       |
| Temperature characteristic of Vdetn | $\frac{\Delta V_{detn}}{\Delta Top}$ | Top=-40~+85°C                                 |                | +100           |                | ppm/°C |       |

\* Ioutp cannot be applied to N-ch opendrain output products. \* Note : test circuit No.

Vdetn=2.7V (ELM7527xxB)

Top=25°C

| Parameter                           | Symbol                               | Condition                                     | Min.           | Typ.           | Max.           | Unit   | Note  |
|-------------------------------------|--------------------------------------|---|----------------|----------------|----------------|--------|-------|
| Detection voltage                   | Vdetn                                |   | 2.646          | 2.700          | 2.754          | V      | 2     |
| Hysteresis width                    | Vhys                                 |   | Vdetn<br>×0.02 | Vdetn<br>×0.04 | Vdetn<br>×0.08 | V      | 2     |
| Current consumption                 | I <sub>ss</sub>                      | V <sub>dd</sub> =4.5V                         |                | 0.6            | 2.0            | μA     | 1     |
| Power voltage                       | V <sub>dd</sub>                      |   | 0.8            |                | 6.0            | V      | 2     |
| Output current                      | I <sub>outn</sub>                    | V <sub>dd</sub> =0.95V, V <sub>ds</sub> =0.4V | 0.03           | 0.12           |                | mA     | 3-(1) |
|                                     |                                      | V <sub>dd</sub> =1.40V, V <sub>ds</sub> =0.4V | 0.60           | 1.40           |                |        |       |
|                                     | I <sub>outp</sub>                    | V <sub>dd</sub> =4.50V, V <sub>ds</sub> =0.4V | 0.20           | 0.60           |                |        | 3-(2) |
| Delay time                          | T <sub>plh</sub>                     | V <sub>dd</sub> =0.95V~4.50V                  |                | 10             |                | μs     | 4     |
|                                     | T <sub>p<sub>hl</sub></sub>          | V <sub>dd</sub> =4.50V~0.95V                  |                | 10             |                |        |       |
| Temperature characteristic of Vdetn | $\frac{\Delta V_{detn}}{\Delta Top}$ | Top=-40~+85°C                                 |                | +100           |                | ppm/°C |       |

\* Ioutp cannot be applied to N-ch opendrain output products. \* Note : test circuit No.

Vdetn=3.0V (ELM7530xxB)

Top=25°C

| Parameter                           | Symbol                               | Condition                                     | Min.           | Typ.           | Max.           | Unit   | Note  |
|-------------------------------------|--------------------------------------|---|----------------|----------------|----------------|--------|-------|
| Detection voltage                   | Vdetn                                |   | 2.940          | 3.000          | 3.060          | V      | 2     |
| Hysteresis width                    | Vhys                                 |   | Vdetn<br>×0.02 | Vdetn<br>×0.04 | Vdetn<br>×0.08 | V      | 2     |
| Current consumption                 | I <sub>ss</sub>                      | V <sub>dd</sub> =4.5V                         |                | 0.6            | 2.0            | μA     | 1     |
| Power voltage                       | V <sub>dd</sub>                      |   | 0.8            |                | 6.0            | V      | 2     |
| Output current                      | I <sub>outn</sub>                    | V <sub>dd</sub> =0.95V, V <sub>ds</sub> =0.4V | 0.03           | 0.12           |                | mA     | 3-(1) |
|                                     |                                      | V <sub>dd</sub> =1.40V, V <sub>ds</sub> =0.4V | 0.60           | 1.40           |                |        |       |
|                                     | I <sub>outp</sub>                    | V <sub>dd</sub> =4.50V, V <sub>ds</sub> =0.4V | 0.20           | 0.60           |                |        | 3-(2) |
| Delay time                          | T <sub>plh</sub>                     | V <sub>dd</sub> =0.95V~4.50V                  |                | 10             |                | μs     | 4     |
|                                     | T <sub>p<sub>hl</sub></sub>          | V <sub>dd</sub> =4.50V~0.95V                  |                | 10             |                |        |       |
| Temperature characteristic of Vdetn | $\frac{\Delta V_{detn}}{\Delta Top}$ | Top=-40~+85°C                                 |                | +100           |                | ppm/°C |       |

\* Ioutp cannot be applied to N-ch opendrain output products. \* Note : test circuit No.

# ELM75xxxxB CMOS Small package voltage detector

Vdetn=3.5V (ELM7535xxB)

Top=25°C

| Parameter                           | Symbol                                  | Condition                                     | Min.           | Typ.           | Max.           | Unit   | Note  |
|-------------------------------------|---|---|----------------|----------------|----------------|--------|-------|
| Detection voltage                   | Vdetn                                   |   | 3.430          | 3.500          | 3.570          | V      | 2     |
| Hysteresis width                    | Vhys                                    |   | Vdetn<br>×0.02 | Vdetn<br>×0.04 | Vdetn<br>×0.08 | V      | 2     |
| Current consumption                 | I <sub>ss</sub>                         | V <sub>dd</sub> =4.5V                         |                | 0.6            | 2.0            | μA     | 1     |
| Power voltage                       | V <sub>dd</sub>                         |   | 0.8            |                | 6.0            | V      | 2     |
| Output current                      | I <sub>outn</sub>                       | V <sub>dd</sub> =0.95V, V <sub>ds</sub> =0.4V | 0.03           | 0.12           |                | mA     | 3-(1) |
|                                     |   | V <sub>dd</sub> =1.40V, V <sub>ds</sub> =0.4V | 0.60           | 1.40           |                |        |       |
|                                     | I <sub>outp</sub>                       | V <sub>dd</sub> =4.50V, V <sub>ds</sub> =0.4V | 0.20           | 0.60           |                |        | 3-(2) |
| Delay time                          | T <sub>plh</sub>                        | V <sub>dd</sub> =0.95V~4.50V                  |                | 10             |                | μs     | 4     |
|                                     | T <sub>p<sub>hl</sub></sub>             | V <sub>dd</sub> =4.50V~0.95V                  |                | 10             |                |        |       |
| Temperature characteristic of Vdetn | $\frac{\Delta V_{detn}}{\Delta T_{op}}$ | T <sub>op</sub> =-40~+85°C                    |                | +100           |                | ppm/°C |       |

\* I<sub>outp</sub> cannot be applied to N-ch opendrain output products. \* Note : test circuit No.

Vdetn=4.0V (ELM7540xxB)

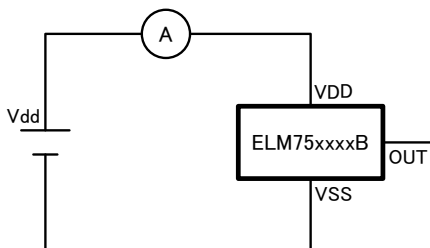
Top=25°C

| Parameter                           | Symbol                                  | Condition                                     | Min.           | Typ.           | Max.           | Unit   | Note  |
|-------------------------------------|---|---|----------------|----------------|----------------|--------|-------|
| Detection voltage                   | Vdetn                                   |   | 3.920          | 4.000          | 4.080          | V      | 2     |
| Hysteresis width                    | Vhys                                    |   | Vdetn<br>×0.02 | Vdetn<br>×0.04 | Vdetn<br>×0.08 | V      | 2     |
| Current consumption                 | I <sub>ss</sub>                         | V <sub>dd</sub> =4.5V                         |                | 0.6            | 2.0            | μA     | 1     |
| Power voltage                       | V <sub>dd</sub>                         |   | 0.8            |                | 6.0            | V      | 2     |
| Output current                      | I <sub>outn</sub>                       | V <sub>dd</sub> =0.95V, V <sub>ds</sub> =0.4V | 0.03           | 0.12           |                | mA     | 3-(1) |
|                                     |   | V <sub>dd</sub> =1.40V, V <sub>ds</sub> =0.4V | 0.60           | 1.40           |                |        |       |
|                                     | I <sub>outp</sub>                       | V <sub>dd</sub> =4.50V, V <sub>ds</sub> =0.4V | 0.20           | 0.60           |                |        | 3-(2) |
| Delay time                          | T <sub>plh</sub>                        | V <sub>dd</sub> =0.95V~4.50V                  |                | 10             |                | μs     | 4     |
|                                     | T <sub>p<sub>hl</sub></sub>             | V <sub>dd</sub> =4.50V~0.95V                  |                | 10             |                |        |       |
| Temperature characteristic of Vdetn | $\frac{\Delta V_{detn}}{\Delta T_{op}}$ | T <sub>op</sub> =-40~+85°C                    |                | +100           |                | ppm/°C |       |

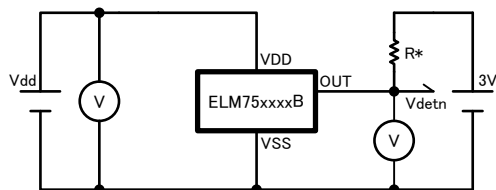
\* I<sub>outp</sub> cannot be applied to N-ch opendrain output products. \* Note : test circuit No.

## Test circuits

### 1) Current consumption



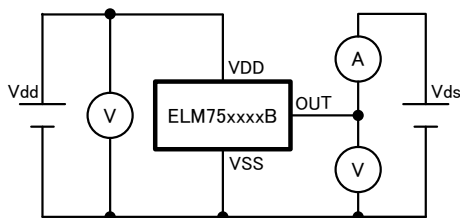
### 2) Detection voltage



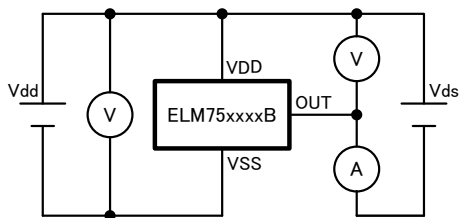
\* Pull up circuit is necessary for N-ch output only.  
\* R=100KΩ (R=2MΩ for V<sub>dd</sub> min measurement.)

# ELM75xxxxB CMOS Small package voltage detector

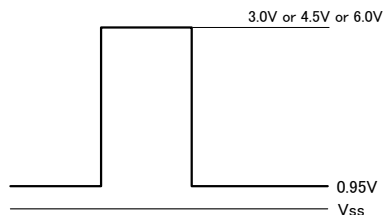
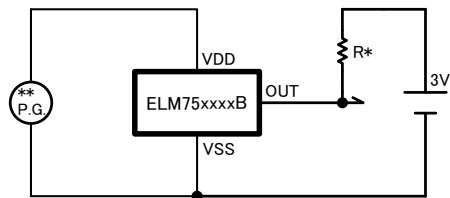
3)-(1) Output current (N-ch)



3)-(2) Output current (P-ch)



4) Delay time

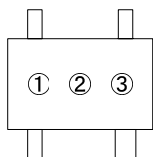


\* Pull up circuit is necessary for N-ch output only.  
\* R=100K $\Omega$

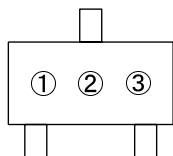
\*\* Input pulse

## ■ Marking

SC-82AB



SC-70



• SC-82AB package • SC-70 package

No. ① : Detection voltage

| Mark | Vdetn | Mark | Vdetn | Mark | Vdetn |
|------|-------|------|-------|------|-------|
| Y    | 1.4V  | G    | 2.8V  | 5    | 4.2V  |
| Z    | 1.5V  | H    | 2.9V  | 6    | 4.3V  |
| 1    | 1.6V  | J    | 3.0V  | =    | 4.4V  |
| 2    | 1.7V  | K    | 3.1V  | 7    | 4.5V  |
| 3    | 1.8V  | L    | 3.2V  | *    | 4.6V  |
| 4    | 1.9V  | M    | 3.3V  | +    | 4.7V  |
| V    | 2.0V  | N    | 3.4V  | -    | 4.8V  |
| W    | 2.1V  | P    | 3.5V  | >    | 4.9V  |
| A    | 2.2V  | Q    | 3.6V  | 8    | 5.0V  |
| B    | 2.3V  | R    | 3.7V  | 9    | 5.1V  |
| C    | 2.4V  | S    | 3.8V  | 0    | 5.2V  |
| D    | 2.5V  | T    | 3.9V  | <    | 5.3V  |
| E    | 2.6V  | U    | 4.0V  | /    | 5.4V  |
| F    | 2.7V  | #    | 4.1V  | X    | 5.5V  |

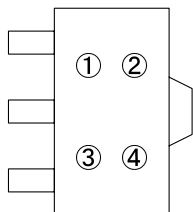
No. ② : Assembly lot No.

A~Z (I, O, X excepted) : N-ch  
0~9 : CMOS

No. ③ : Assembly lot No.

0~9 : N-ch  
A~Z (I, O, X excepted) : CMOS

SOT-89



## • SOT-89 package

No. ① : the integer digit of detection voltage

| Mark | Vdetn | Mark | Vdetn |
|------|-------|------|-------|
| 9    | 1.*V  | 8    | 4.*V  |
| 6    | 2.*V  | X    | 5.*V  |
| 7    | 3.*V  |      |       |

No. ② : the decimal digit of detection voltage

| Mark | Vdetn | Mark | Vdetn |
|------|-------|------|-------|
| 0    | *.0V  | 5    | *.5V  |
| 1    | *.1V  | 6    | *.6V  |
| 2    | *.2V  | 7    | *.7V  |
| 3    | *.3V  | 8    | *.8V  |
| 4    | *.4V  | 9    | *.9V  |

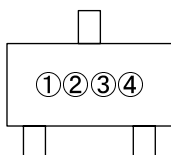
No. ③ : Assembly lot No.

A~Z (I, O, X excepted) : N-ch  
0~9 : CMOS

No. ④ : Assembly lot No.

0~9 : N-ch  
A~Z (I, O, X excepted) : CMOS

SOT-23



## • SOT-23 package

No. ① : the integer digit of detection voltage

| Mark | Vdetn | Mark | Vdetn |
|------|-------|------|-------|
| 0    | 1.*V  | 9    | 4.*V  |
| 7    | 2.*V  | X    | 5.*V  |
| 8    | 3.*V  |      |       |

No. ② : the decimal digit of detection voltage

| Mark | Vdetn | Mark | Vdetn |
|------|-------|------|-------|
| 0    | *.0V  | 5    | *.5V  |
| 1    | *.1V  | 6    | *.6V  |
| 2    | *.2V  | 7    | *.7V  |
| 3    | *.3V  | 8    | *.8V  |
| 4    | *.4V  | 9    | *.9V  |

No. ③ : Assembly lot No.

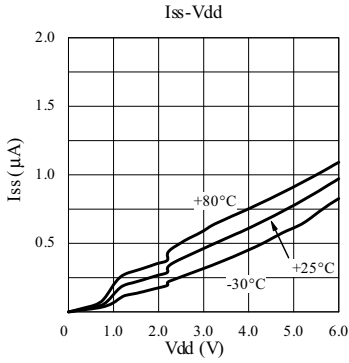
A~Z (I, O, X excepted) : N-ch  
0~9 : CMOS

No. ④ : Assembly lot No.

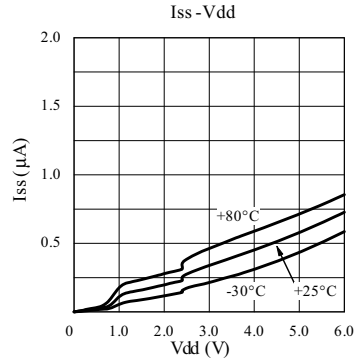
0~9 : N-ch  
A~Z (I, O, X excepted) : CMOS

## Current consumption characteristics

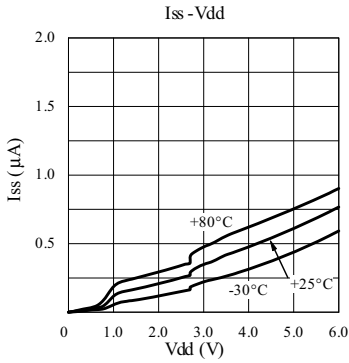
• ELM7522xxB



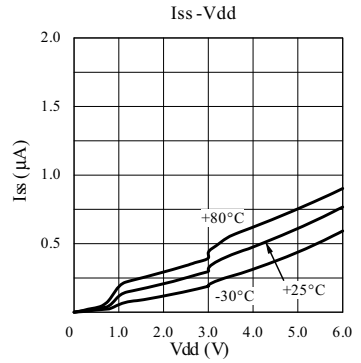
• ELM7524xxB



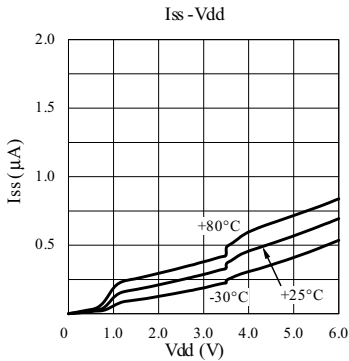
• ELM7527xxB



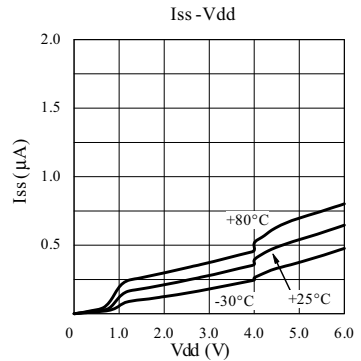
• ELM7530xxB



• ELM7535xxB



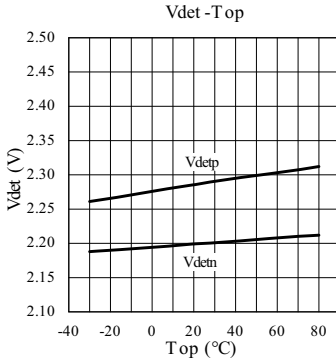
• ELM7540xxB



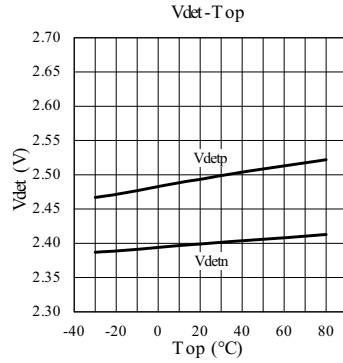


## ■ Detection voltage characteristics

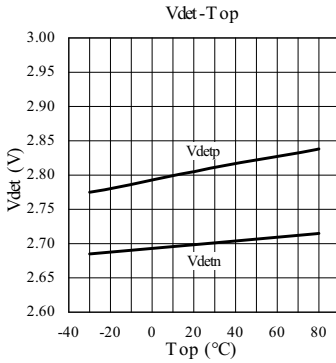
• ELM7522xxB



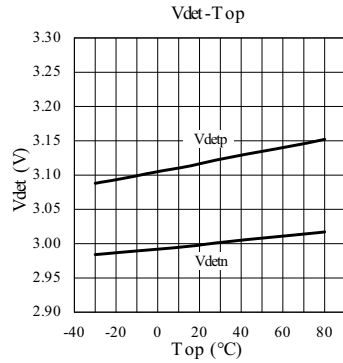
• ELM7524xxB



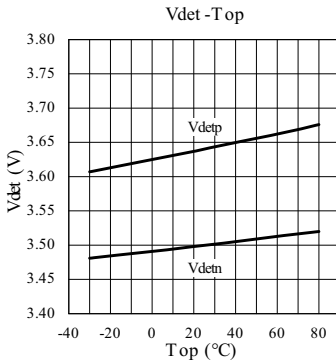
• ELM7527xxB



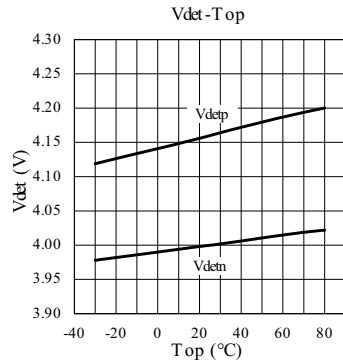
• ELM7530xxB



• ELM7535xxB

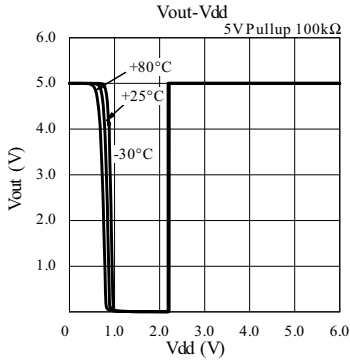


• ELM7540xxB

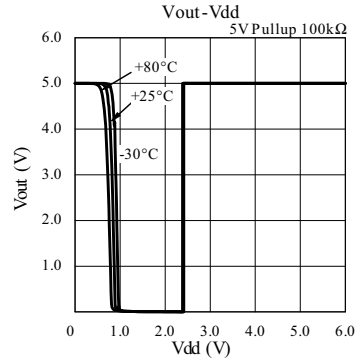


## Output voltage characteristics

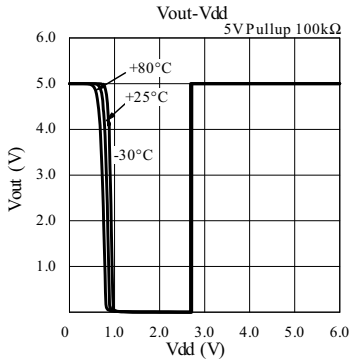
• ELM7522NxB



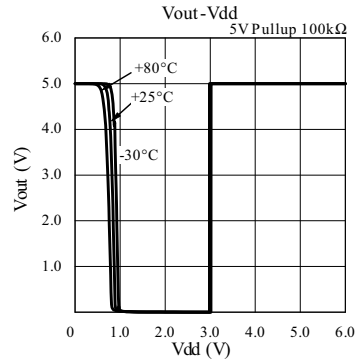
• ELM7524NxB



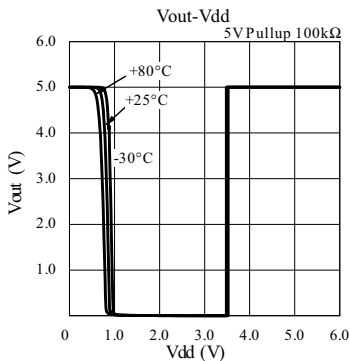
• ELM7527NxB



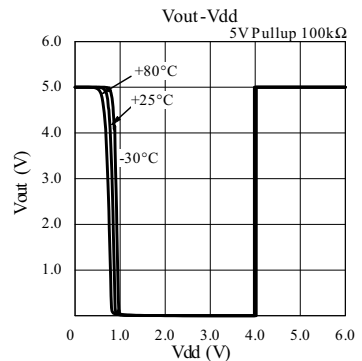
• ELM7530NxB



• ELM7535NxB

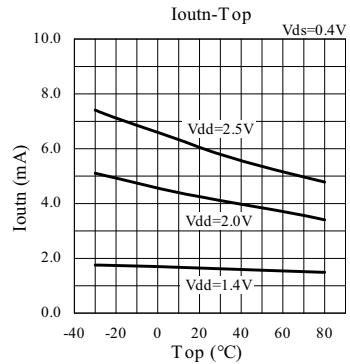
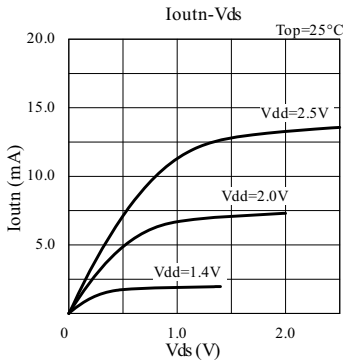
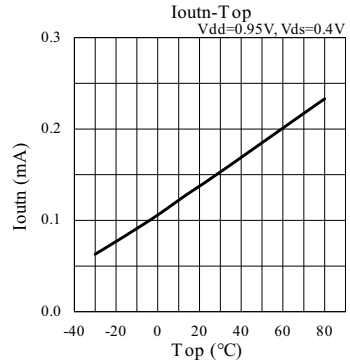
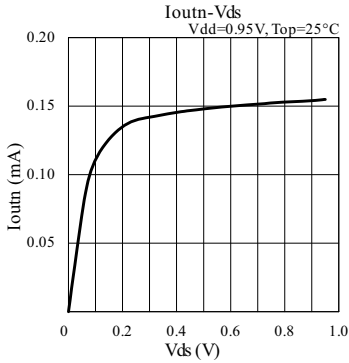


• ELM7540NxB

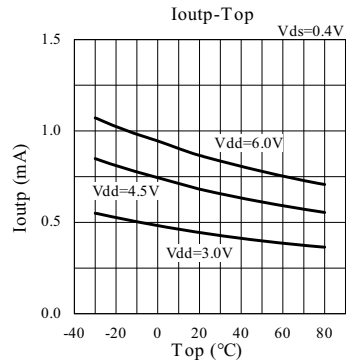
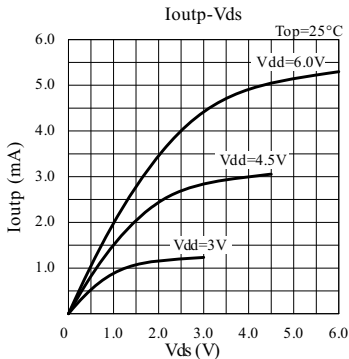


## Output current characteristics

- ELM75xxxxB

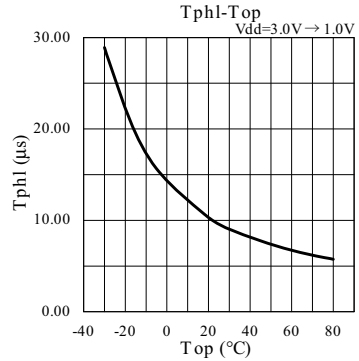
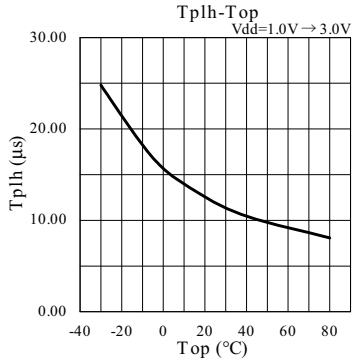


- ELM75xxCxB

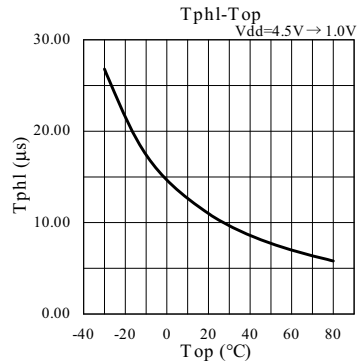
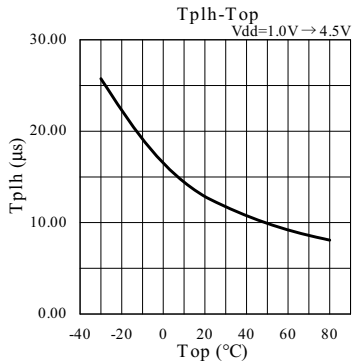


## ■ Delay time characteristics

- ELM7522xxB, ELM7524xxB



- ELM7527xxB, ELM7530xxB, ELM7535xxB, ELM7540xxB



## ■ Hysteresis width characteristics

- ELM75xxxxB

